GW109 / GW209 SUPERCAPACITOR
Datasheet Rev 4.1, October 2015

This Datasheet should be read in conjunction with the CAP-XX Supercapacitors Product Guide which contains information common to our product lines.

Electrical Specifications

The GW109 is a single cell supercapacitor. The GW209 is a dual cell supercapacitor with two GW109 cells in series, so GW209 capacitance = Capacitance of GW109/2 and GW209 ESR = 2 x GW109 ESR.

Table 1: Absolute Maximum Ratings

Parameter	Name		Conditions	Min		Max	Units
Terminal Voltage	Vpeak	GW109		0		2.75	V
		GW209				5.5	
Temperature	Tmax			-40		+70	°C

Table 2: Electrical Characteristics

Parameter	Name		Conditions	Min	Typical	Max	Units
Terminal Voltage	V_n	GW109		0		2.5	V
		GW209		0		5.0	
Capacitance	C	GW109	DC, 23°C	256	320	384	mF
		GW209		128	160	192	
ESR	ESR	GW109	DC, 23°C	18	22	26	mΩ
		GW209		36	45	54	
Leakage Current	I_L		2.3V, 23°C 120hrs		0.5	1	μA
RMS Current	I_{RMS}		23°C			6	A
Peak Current[1]	I_P		23°C			30	A

[1]Non-repetitive current, single pulse to discharge fully charged supercapacitor.

Table 3: Thickness

GW109F	1.0mm	No adhesive tape on underside of the supercapacitor	GW109G	1.10mm	Adhesive tape on underside, release tape removed
GW209F	2.0mm		GW209G	2.10mm	

Definition of Terms

In its simplest form, the Equivalent Series Resistance (ESR) of a capacitor is the real part of the complex impedance. In the time domain, it can be found by applying a step discharge current to a charged cell as in Fig. 1. In this figure, the supercapacitor is pre-charged and then discharged with a current pulse, I =1A for duration 0.01 secs.
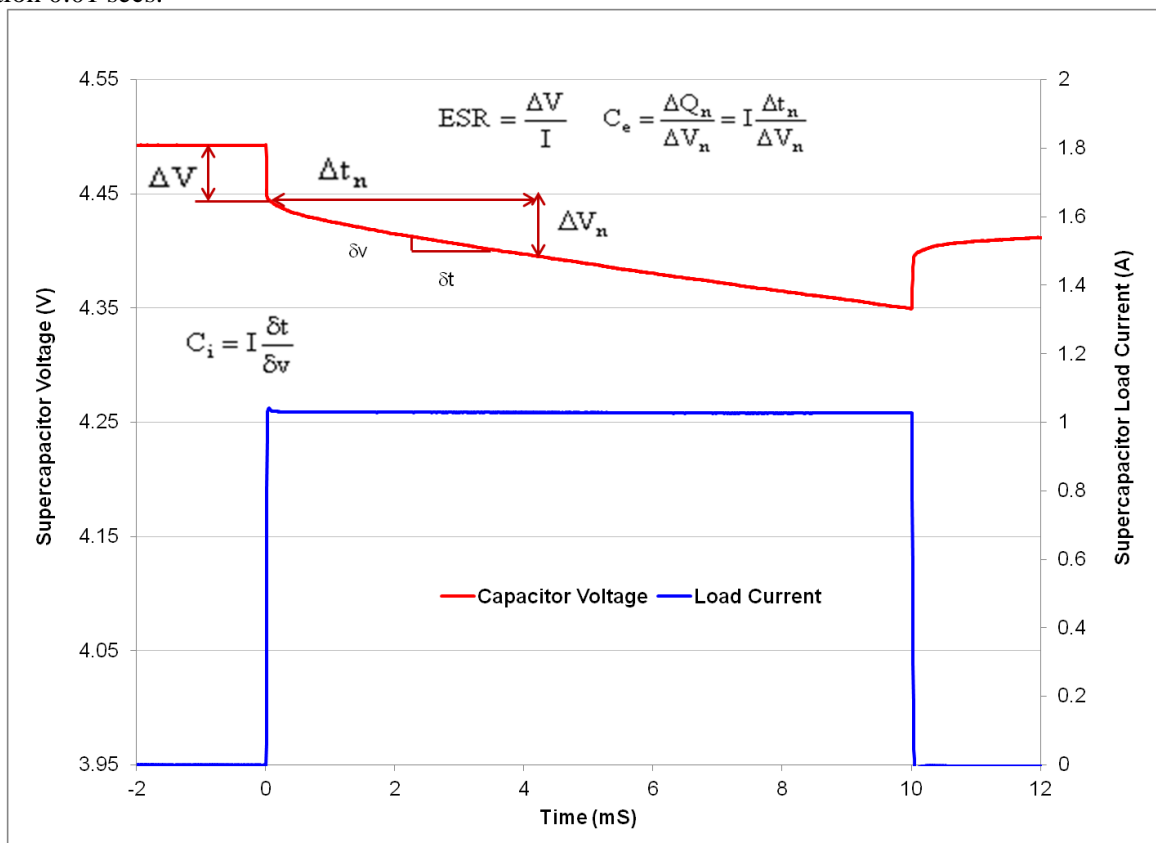

The figure shows equations:
$$ESR = \frac{\Delta V}{I} \qquad C_e = \frac{\Delta Q_n}{\Delta V_n} = I \frac{\Delta t_n}{\Delta V_n}$$

$$C_i = I \frac{\delta t}{\delta v}$$

Figure 1: Effective capacitance, instantaneous capacitance and ESR for a GW209

The ESR is found by dividing the instantaneous voltage step (ΔV) by I. In this example = (4.492V-4.447V)/1.03A = 43.7mΩ.

The instantaneous capacitance (C_i) can be found by taking the inverse of the derivative of the voltage, and multiplying it by I.

The effective capacitance for a pulse of duration Δt_n, Ce(Δt_n) is found by dividing the total charge removed from the capacitor (ΔQ_n) by the voltage lost by the capacitor (ΔV_n). For constant current Ce(Δt_n) = I x $\Delta t_n/\Delta V_n$. Ce increases as the pulse width increases and tends to the DC capacitance value as the pulse width becomes very long (~10 secs). After 2msecs, Fig 1 shows the voltage drop V_{2ms} = (4.447V – 4.414V) = 33mV. Therefore Ce(2ms) = 1.03A x 2ms/33mV = 62.4mF. After 10ms, the voltage drop = 4.447 V – 4.349V = 98mV. Therefore Ce(10ms) = 1.03A x 10ms/98mV = 105mF. The DC capacitance of a GW209 = 160mF. Note that ΔV, or IR drop, is not included because very little charge is removed from the capacitor during this time. Ce shows the time response of the capacitor and it is useful for predicting circuit behavior in pulsed applications.
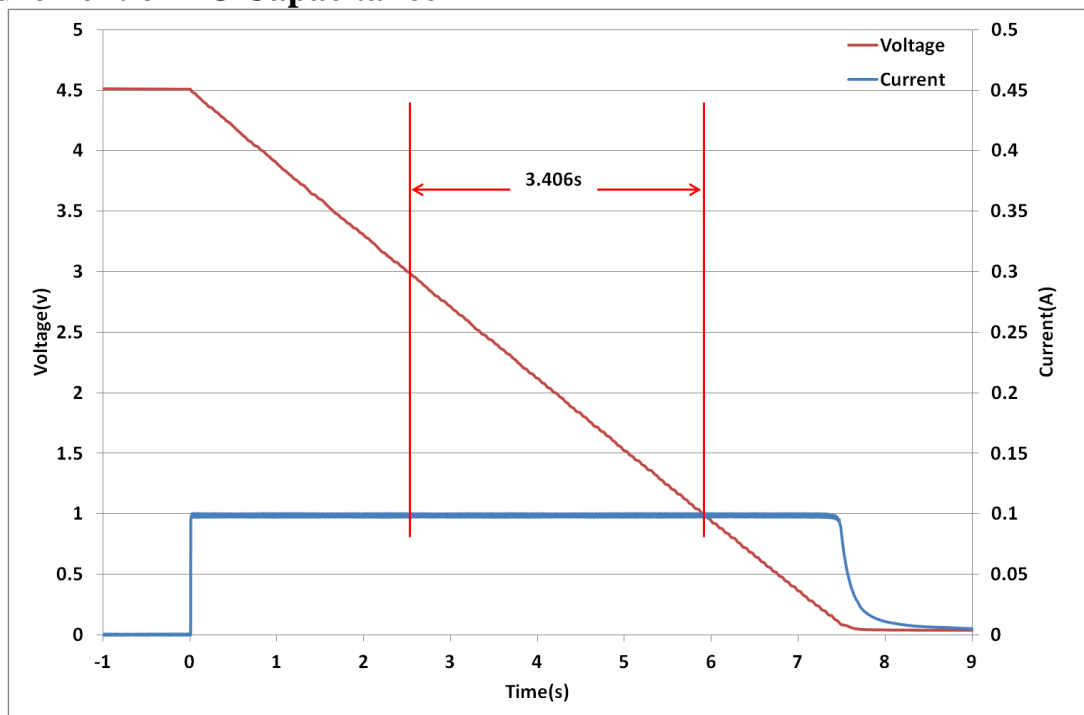
Measurement of DC Capacitance

Fig 2: Measurement of DC Capacitance for a GW209

Fig 2 shows the measurement of DC capacitance by drawing a constant 100mA current from a fully charged supercapacitor and measuring the time taken to discharge from 1.5V to 0.5V for a single cell, or from 3V to 1V for a dual cell supercapacitor. In this case, C = 0.1A x 3.406s /2V = 170.3mF, which is well within the 160mF +/- 20% tolerance for a GW209 cell.
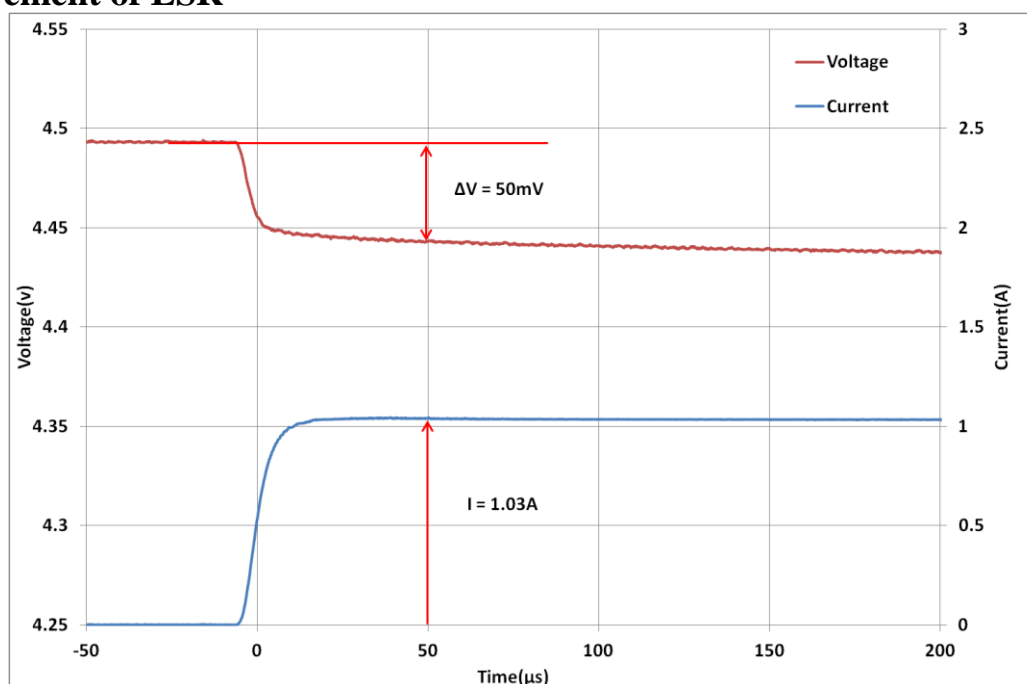
Measurement of ESR

Fig 3: Measurement of ESR for a GW209

Fig 3 shows DC measurement of ESR by applying a step load current to the supercapacitor and measuring the resulting voltage drop. CAP-XX waits for a delay of 50µs after the step current is applied to ensure the voltage and current have settled. In this case the ESR is measured as 50mV/1.03A = 48.5mΩ.
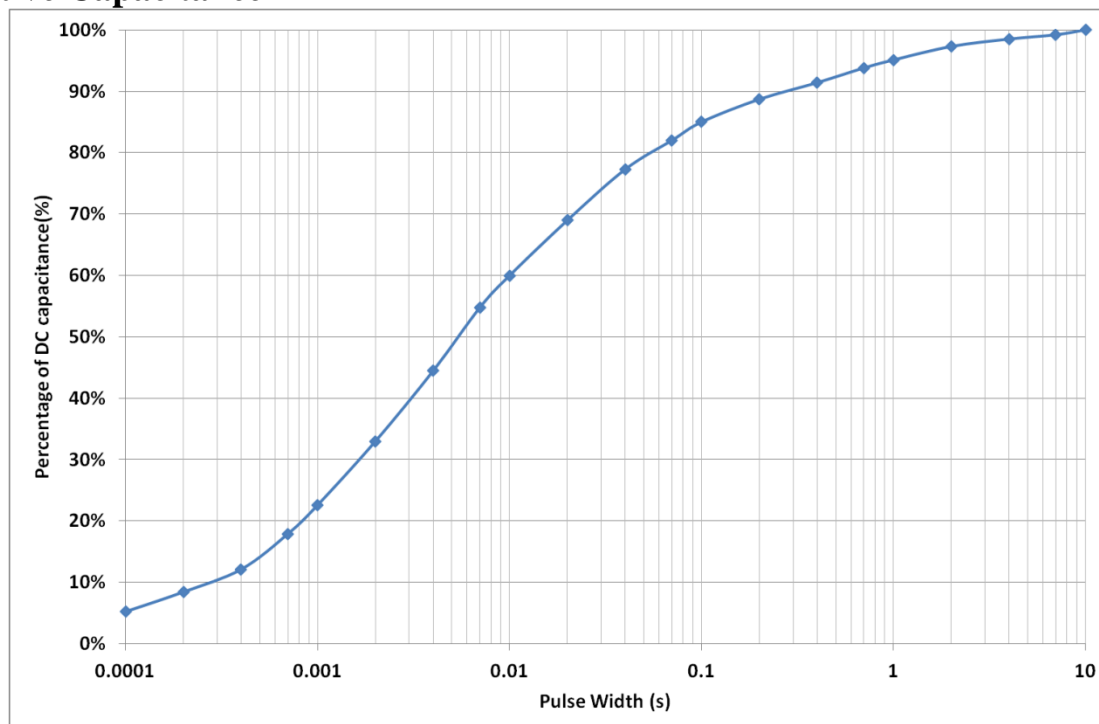
Effective Capacitance

Figure 4: Effective Capacitance

Fig 4 shows the effective capacitance for the GW109, GW209 @ 23°C. This shows that for a 1msec PW, you will measure 22.6% of DC capacitance or 63.3mF for a GW109 or 31.6mF for a GW209. At 10msecs you will measure 60% of the DC capacitance, and at 100msecs you will measure 85% of DC capacitance. Ceffective is a time domain representation of the supercapacitor's frequency response. If, for example, you were calculating the voltage drop if the supercapacitor was supporting 1A for 10msecs, then you would use the Ceff(10msecs) = 60% of DC capacitance = 96mF for a GW209, so Vdrop = 1A x ESR + 1A x duration/C = 1A x 45mΩ + 1A x 10ms / 96mF = 149mV. The next section on pulse response shows how the effective capacitance is sufficient for even short pulse widths.
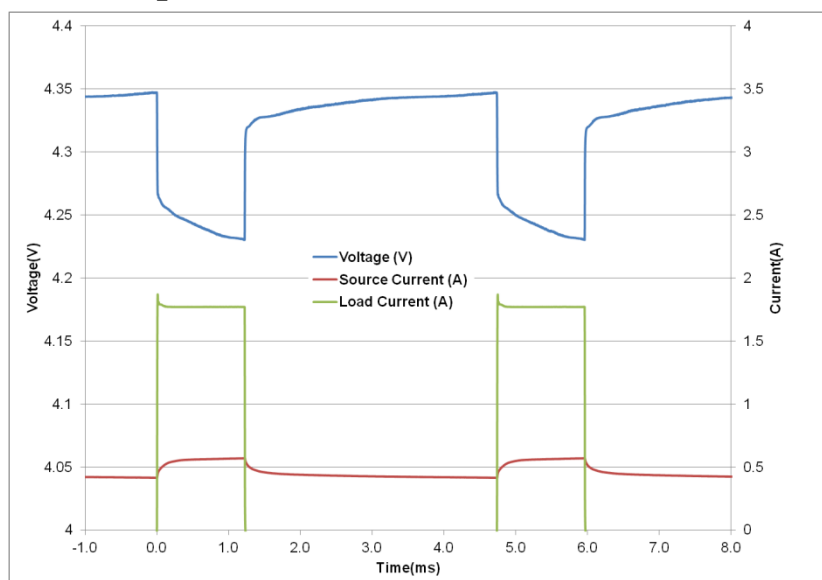
Pulse Response

Fig 5 shows that the GW209 supercapacitor does an excellent job supporting a GPRS class 10 pulse train, drawing 1.8A for 1.1ms at 25% duty cycle. The source is current limited to 0.6A and the supercapacitor provides the 1.2A difference to achieve the peak current. At first glance the freq response of Fig 8 indicates the supercapacacitor would not support a 1ms pulse, but the Ceff of 31.6mF coupled with the low ESR supports this pulse train with only ~117mV droop in the supply rail.

Fig 5: GW209 Pulse Response with GPRS Class 10 Pulse Train
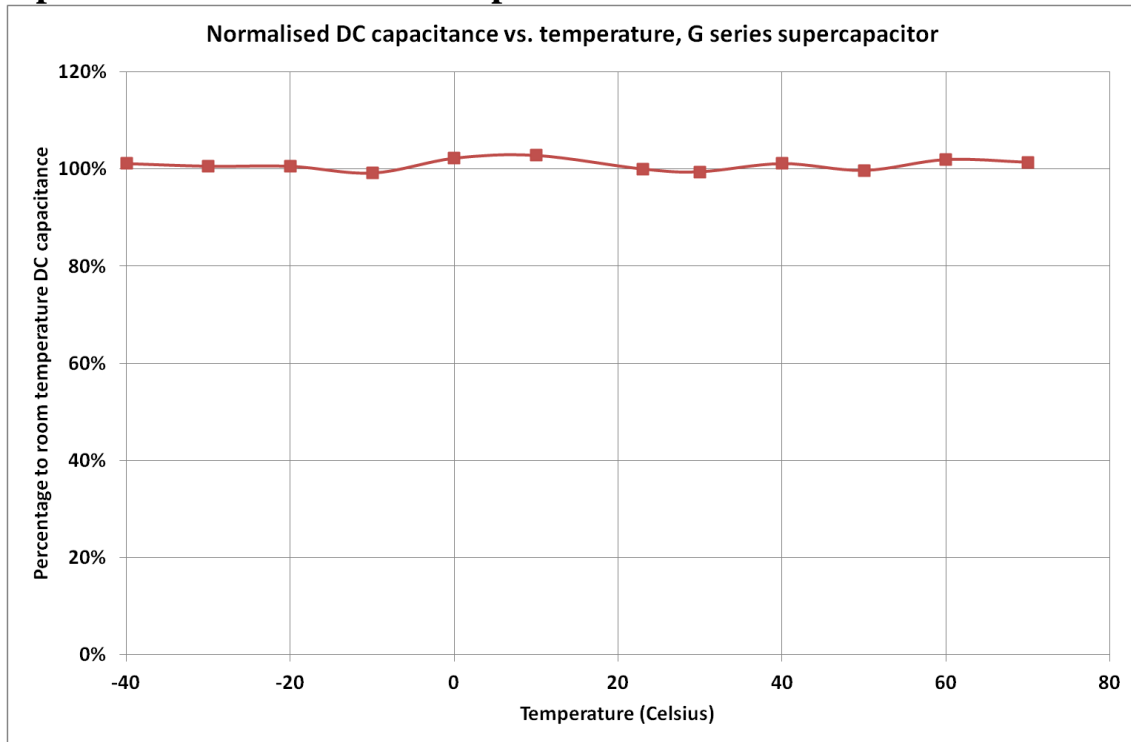
DC Capacitance variation with temperature

Figure 6: Capacitance change with temperature

Fig 6 shows that DC capacitance is approximately constant with temperature.

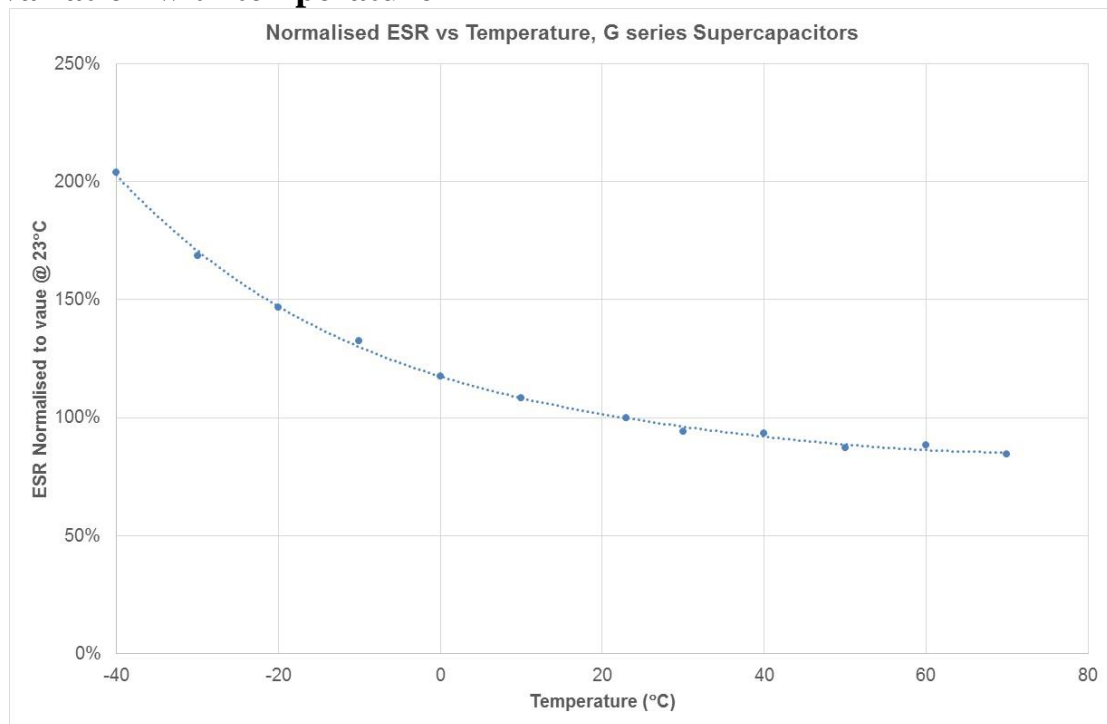## ESR variation with temperature

Figure 7: ESR change with temperature

Fig 7 shows that ESR at -40°C is ~2.2 x ESR at room temp, and that ESR at 70ºC is ~0.82 x ESR at room temperature.
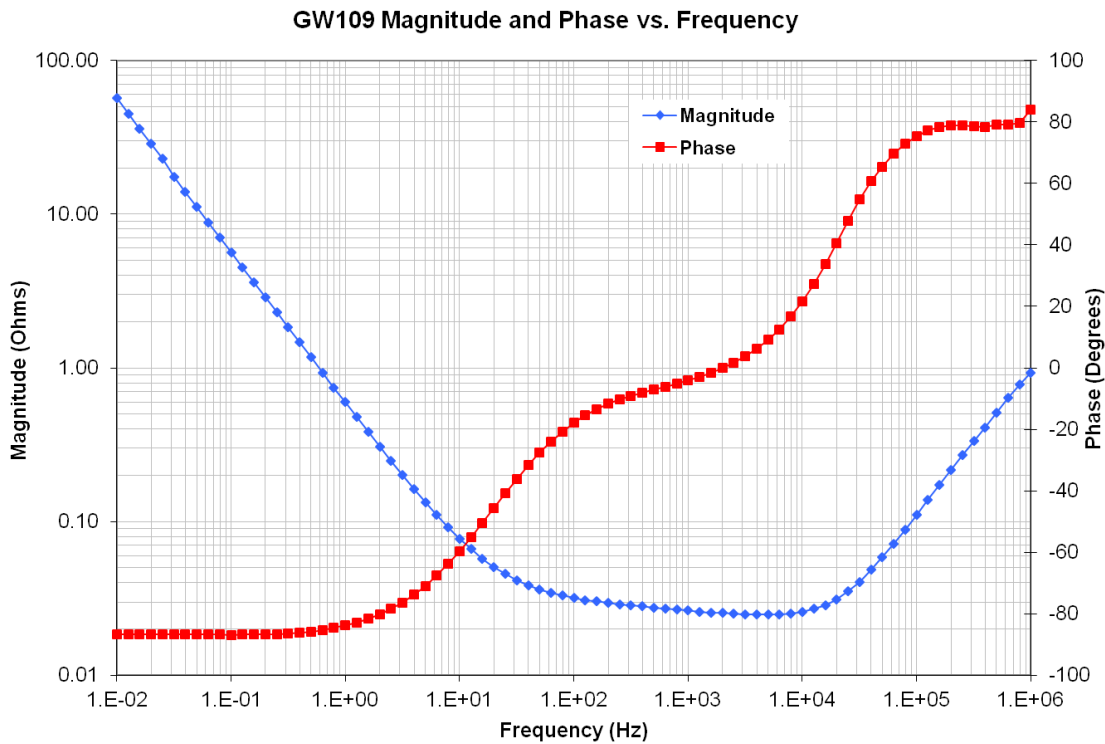
Frequency Response

GW109 Magnitude and Phase vs. Frequency

Fig 8: Frequency Response of Impedance (biased at 2.3V with a 50mV test signal)

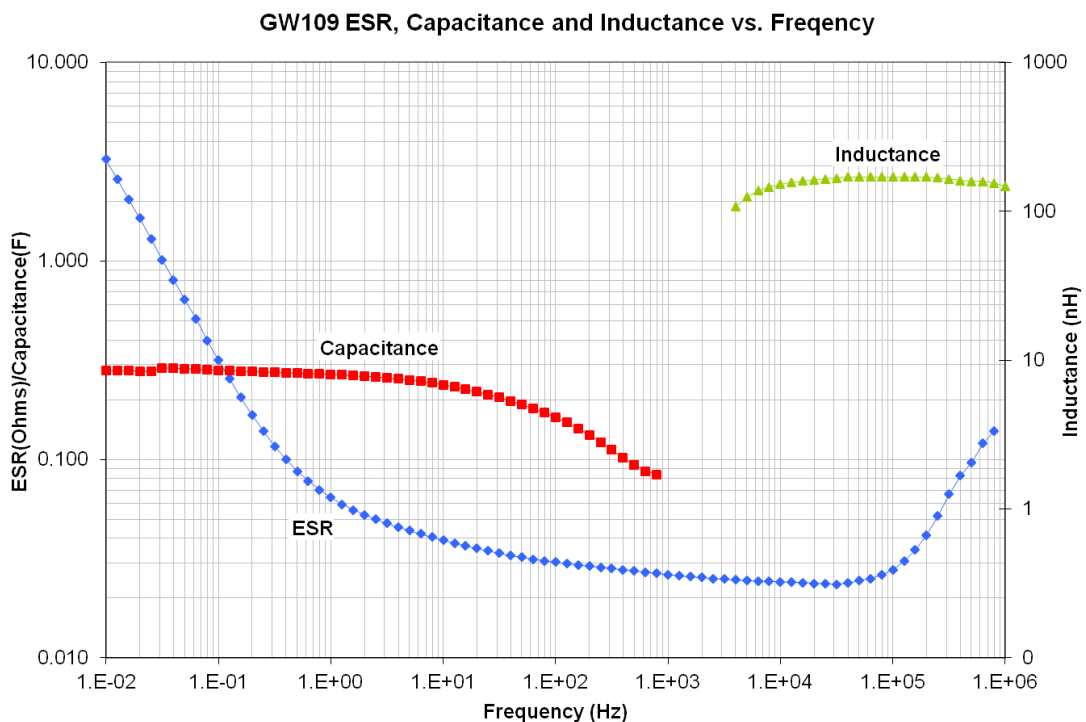**GW109 ESR, Capacitance and Inductance vs. Freqency**

Fig 9: Frequency Response of ESR, Capacitance & Inductance

Fig 8 shows the supercapacitor behaves as an ideal capacitor until approx 10 Hz when the magnitude no longer rolls off proportionally to 1/freq and the phase crosses -45°. Performance of supercapacitors with frequency is complex and the best predictor of performance is Fig 4 showing effective capacitance as a function of pulsewidth.
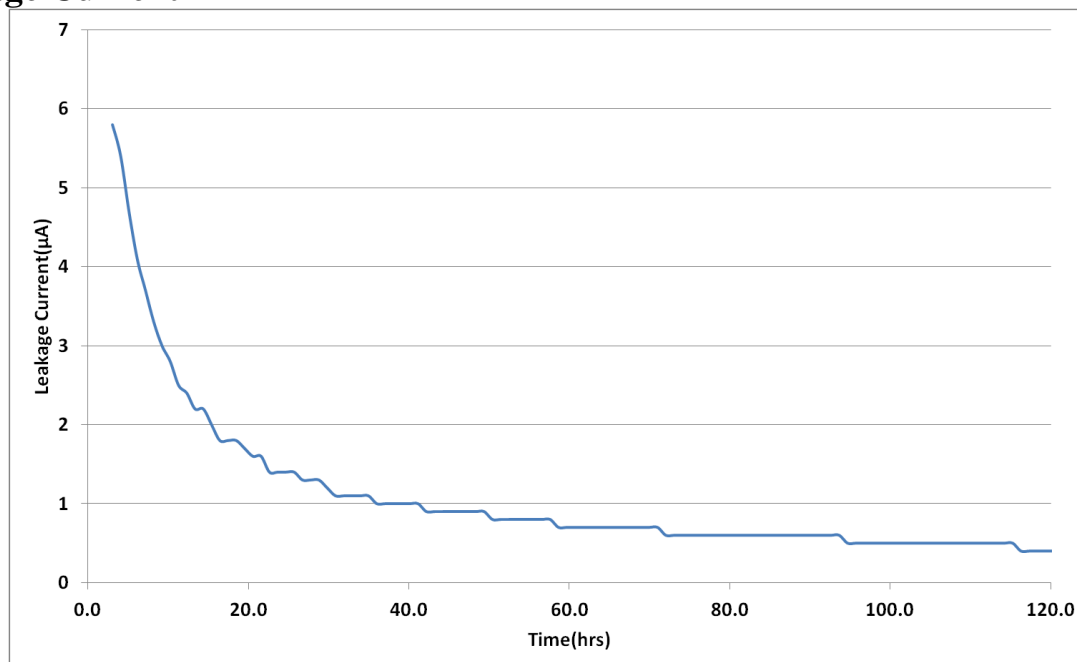
Leakage Current

Fig 10: Leakage Current

Fig 10 shows the leakage current for GW109 at room temperature. The leakage current decays over time and the equilibrium value leakage current will be reached after ~120hrs at room temperature. The typical equilibrium leakage current is 0.5μA at room temperature. At 70°C leakage current will be ~5μA.
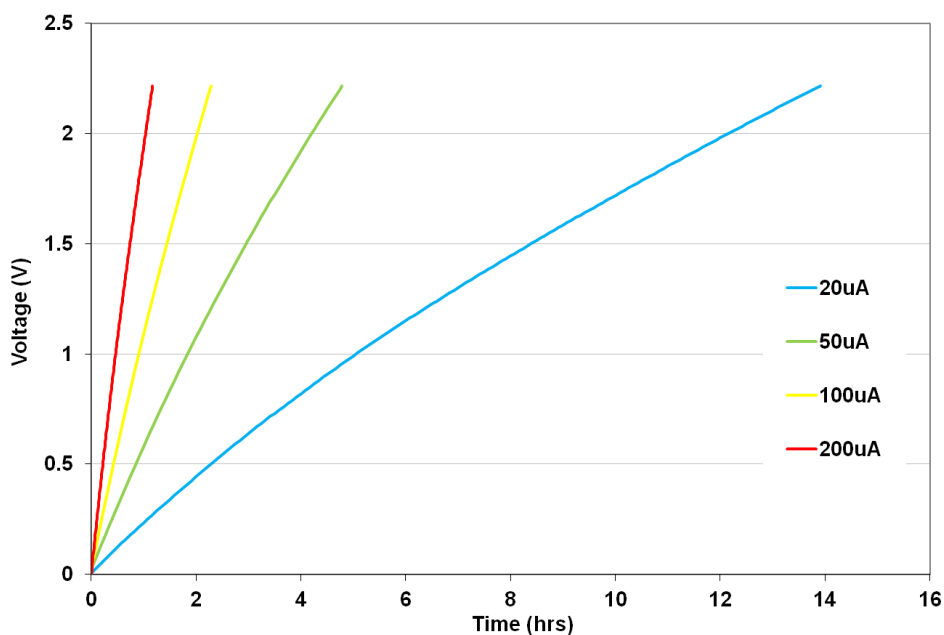
Charge Current

Fig 11: Charging an GW109 with low current

The corollary to the slow decay in leakage currents shown in Fig 10 is that charging a supercapacitor at very low currents takes longer than theory predicts. At higher charge currents, the charge rate is as theory predicts. For example, it should take 0.32F x 2.3V / 0.00002A = 10 hrs to charge a 0.16F supercapacitor to 2.3V at 20μA, but Fig 11 shows it took 14hrs. At 100μA charging occurs at a rate close to the theoretical rate.
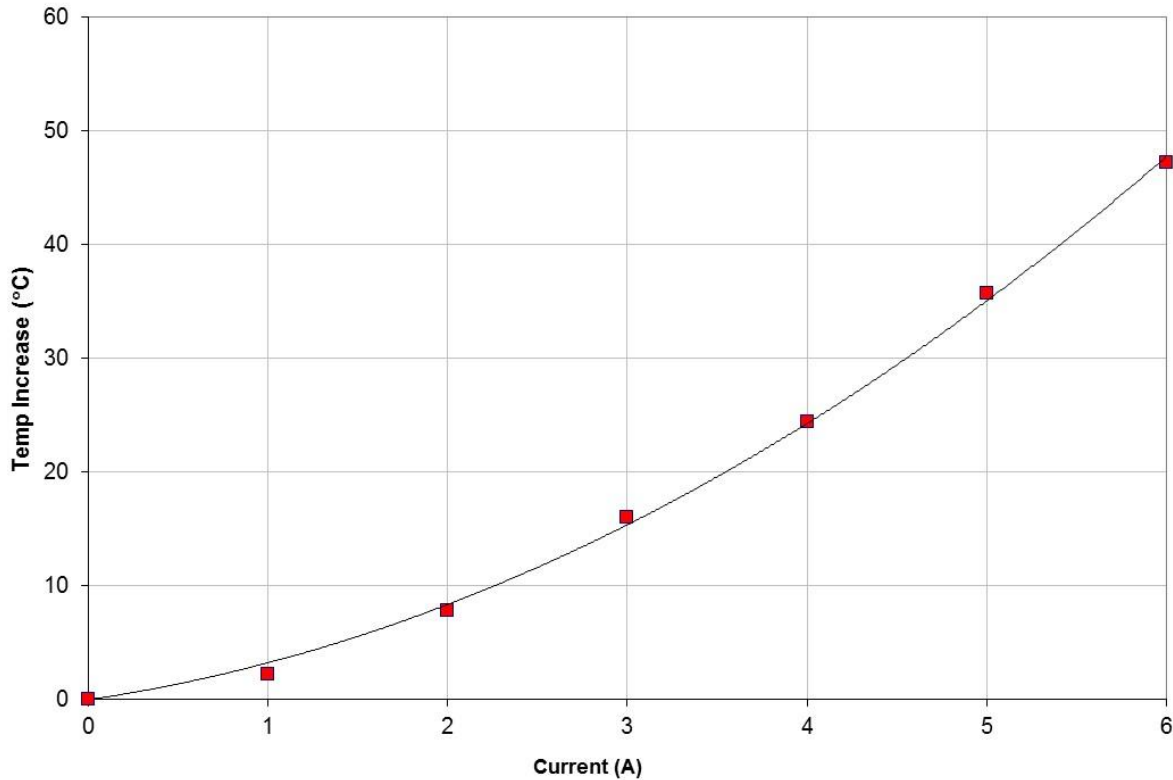
RMS Current

Fig 12: Temperature rise in GW209 with RMS current

Continuous current flow into/out of the supercap will cause self heating, which limits the maximum continuous current the supercapacitor can handle. This is measured by a current square wave with 50% duty cycle, charging the supercapacitor to rated voltage at a constant current, and then discharging the supercapacitor to half rated voltage at the same constant current value. For a square wave with 50% duty cycle, the RMS current is the same as the current amplitude. Fig 12 shows the increase in temperature as a function of RMS current. From this, the maximum RMS current in an application can be calculated, for example, if the ambient temperature is 40°C, and the maximum desired temperature for the supercapacitor is 70°C, then the maximum RMS current should be limited to 4.5A, which causes a 30°C temperature increase.

CAP-XX Supercapacitors Product Guide

Refer to the package drawings in the CAP-XX Supercapacitors Product Guide for detailed information of the product's dimensions, PCB landing placements, active areas and electrical connections.

Refer to the CAP-XX Supercapacitors Product Guide for information on endurance and shelf life, transportation and storage, assembly and soldering, safety and RoHS/EREACH certification.